Generation of pulse duration-tunable optical pulses from an injection-locked gain-switched laser diode

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INTRODUCTION  Optical pulse generation from semiconductor laser diodes are widely used for many applications such as laser machining and bio-imaging \cite{1,2}. Although it is easy for a gain-switched laser diode (GS-LD) to generate optical pulses, it is difficult to obtain duration-tunable smooth-shaped pulses because of the relaxation oscillation feature of an LD. In this report, we describe a method to solve this problem by incorporating GS-operation under CW laser light injection.

EXPERIMENT AND RESULTS  It is predicted by a simple rate-equation analysis that the relaxation oscillation can be suppressed when a proper CW laser light is injected into an LD. This feature is attractive for generating smooth-shaped duration-tunable optical pulses. Based on the analysis, we have carried out experiments to confirm the expected operation properties. In our experiment, we used a distributed-feedback LD (DFB-LD) to generate CW laser light under constant DC current excitation, and a Fabry-Perot LD (FP-LD) for GS operation. By choosing proper operation conditions, we could observe single-mode duration-tunable optical pulses. Figure 1 shows examples for temporal waveforms indicating optical pulses generated from an injection-locked GS-LD (ILGS-LD). The results shown in Fig.1 show that the present method is promising for generating sub-nanosecond to hundreds of nanosecond duration-tunable narrow-bandwidth smooth-shaped optical pulses. We expect the ILGS-LD method will be a real-world technology for very broad applications.

![Fig. 1. Three examples for ILGS-LD optical pulse with different electric pulse durations. Repetition rate: 5MHz. Electrical pulse duration: 300ps for (a), 10ns for (b), 100ns for (c), electrical pulse voltage: 10.6V for (a), 3V for (b)(c). P\textsubscript{inj} is the averaged power for the CW injection laser, P\textsubscript{out} is the averaged optical pulse output power, and PW is the optical pulse width.](image)

Acknowledgement

This work was supported in part by the project of “Research and Development of Next Generation Laser Processing Technology” from New Energy and industrial technology Development Organization(NEDO), and by the Brain Mapping by Integrated Neuroethologies for Disease Studies (Brain/MINDS) from Japan Agency for Medical Research and development(AMED).

References